


	ZXMP6A17N8TC	
	Hersteller-Teilenummer:	ZXMP6A17N8TC
	Hersteller / Marke:	Diodes Incorporated
	Teil der Beschreibung:	MOSFET P-CH 60V 2.7A 8SO
	Datenblätter:	 ZXMP6A17N8TC.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 58148 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	ZXMP6A17N8TC
Hersteller	Diodes Incorporated
Beschreibung	MOSFET P-CH 60V 2.7A 8SO
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	58148 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Verlustleistung (max)	1.56W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.7A (Ta)
Rds On (Max) @ Id, Vgs	125 mOhm @ 2.3A, 10V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17.7nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	637pF @ 30V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Original-Reel®
































ZXMP6A17N8TC ist neu im Original, Suche ZXMP6A17N8TC Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie ZXMP6A17N8TC Diodes Incorporated mit Garantie und Vertrauen. Anfrage ZXMP6A17N8TC: Info@Y-IC.com

Sie können auch interessiert sein:

 ZXMP6A18DN8TC Z ZXMP6A18DN8TC Z	 ZXMP6A18KTC Diodes Incorporated MOSFET P-CH 60V 6.8A DPAK	 ZXMP6A17N8TA VB ZXMP6A17N8TA VB	 ZXMP6A17GTC Z ZXMP6A17GTC Z
 ZXMP6A18K DIODES ZXMP6A18K DIODES	 ZXMP6A17K DIODES ZXMP6A17K DIODES	 ZXMP6A18DN8TA Diodes Incorporated MOSFET 2P-CH 60V 3.7A 8-SOIC	 ZXMP6A18DN8 Diodes Incorporated ZXMP6A18DN8 DIODES

heiße Teile

Mehr

 ZXMP4A57E6	 ZXMP4A57E6TA	 ZXMP6A13FQTA	 ZXMP6A13FTA	 ZXMP6A13G
 ZXMP6A13GTA	 ZXMP6A16DN8	 ZXMP6A16DN8Q	 ZXMP6A16DN8TA	 ZXMP6A16DN8TC
 ZXMP6A16KTC	 ZXMP6A17	 ZXMP6A17DN8	 ZXMP6A17DN8QTC	 ZXMP6A17DN8TA
 ZXMP6A17DN8TC	 ZXMP6A17E6QTA	 ZXMP6A17E6TA	 ZXMP6A17G	 ZXMP6A17G-7-88
 ZXMP6A17GQTA	 ZXMP6A17GTA	 ZXMP6A17GTC	 ZXMP6A17K	 ZXMP6A17KTC
 ZXMP6A17N8	 ZXMP6A17N8TA	 ZXMP6A18DN8	 ZXMP6A18DN8TA	 ZXMP6A18DN8TC
 ZXMP6A18K	 ZXMP6A18KTC	 ZXMP7A17GQTA	 ZXMP7A17GTA	 ZXMP7A17KTC
 ZXMS6001N3QTA	 ZXMS6001N3TA	 ZXMS6002GTA	 ZXMS6004DGTA	 ZXMS6004DT8TA
 ZXMS6004FFQTA	 ZXMS6004FFT	 ZXMS6004FFTA	 ZXMS6004N8-13	 ZXMS6004SGTA
 ZXMS6005DGQTA	 ZXMS6005DGTA	 ZXMS6005SGQTA	 ZXMS6005SGTA	 ZXMS6006DGTA

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